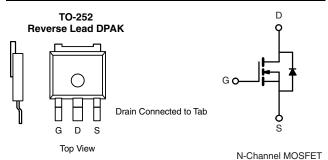


Vishay Siliconix

Automotive N-Channel 100 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	100			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.025			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 4.5 V$	0.029			
I _D (A)	40			
Configuration	Single			



FEATURES

- TrenchFET[®] Power MOSFET
- Package with Low Thermal Resistance
- 100 % $\rm R_g$ and UIS Tested
- AEC-Q101 Qualified
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ORDERING INFORMATION	
Package	TO-252 Reverse Lead DPAK
Lead (Pb)-free and Halogen-free	SQR40N10-25-GE3

ABSOLUTE MAXIMUM RATINGS (T _C =	= 25 °C, unles	s otherwise noted)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	100	V	
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Current	$T_C = 25 \ ^\circ C^a$	1	40		
Continuous Drain Current	T _C = 125 °C	I _D	26		
Continuous Source Current (Diode Conduction) ^a		I _S	40	A	
Pulsed Drain Current ^b		I _{DM}	160		
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	40		
Single Pulse Avalanche Energy	L = 0.1 mm	E _{AS}	80	mJ	
Maximum Power Dissipation ^b	T _C = 25 °C	D	136	w	
	T _C = 125 °C	P _D	45	~~~	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to + 175	С°	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount ^c	R _{thJA}	50	°C/W
Junction-to-Case (Drain)		R _{thJC}	1.1	0/10

Notes

a. Package limited.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

c. When mounted on 1" square PCB (FR-4 material).

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PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT	
Static	-						I
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} :	= 0 V, I _D = 250 μA	100	-	-	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μΑ	1.5	-	2.5	v
Gate-Source Leakage	I _{GSS}	V _{DS} =	$0 \text{ V}, \text{ V}_{\text{GS}} = \pm 20 \text{ V}$	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 100 V	-	-	1	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 100 V, T _J = 125 °C	-	-	50	μA
		$V_{GS} = 0 V$	$V_{DS} = 100 \text{ V}, \text{ T}_{\text{J}} = 175 ^{\circ}\text{C}$	-	-	250	1
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	50	-	-	Α
		$V_{GS} = 10 V$	I _D = 40 A	-	0.019	0.025	$ \begin{array}{c c c c c c c } \hline & & & & & \\ \hline & & & & \\ \hline & & & & \\ \hline & & & &$
Ducia Countra On Otata Desistance?	P	V _{GS} = 10 V	I _D = 40 A, T _J = 125 °C	-	-	0.050	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 40 A, T _J = 175 °C	-	-	0.063	
		$V_{GS} = 4.5 V$	I _D = 20 A	-	0.021	0.029	
Forward Transconductance ^b	9 _{fs}	V _{DS}	= 15 V, I _D = 40 A	-	73	-	S
Dynamic ^b		·					•
Input Capacitance	C _{iss}			-	2703	3380	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	312	390	pF
Reverse Transfer Capacitance	C _{rss}	1		-	127	160	1
Total Gate Charge ^c	Qg			-	46	70	
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = 10 V$	$V_{DS} = 50 \text{ V}, I_D = 40 \text{ A}$	-	8.2	-	nC
Gate-Drain Charge ^c	Q _{gd}	1		-	13	-	
Gate Resistance	R _g		f = 1 MHz	1	2	3.1	Ω
Turn-On Delay Time ^c	t _{d(on)}			-	11	17	
Rise Time ^c	tr	$ \begin{array}{c c} V_{DD} = 50 \text{ V}, \text{R}_{\text{L}} = 1.25 \ \Omega \\ I_{\text{D}} \cong 40 \text{A}, \text{V}_{\text{GEN}} = 10 \text{V}, \text{R}_{\text{g}} = 1 \ \Omega \\ \end{array} \begin{array}{c c} - & 11 \\ \hline - & 27 \end{array} $		11	17		
Turn-Off Delay Time ^c	t _{d(off)}			41			
Fall Time ^c	t _f	1		-	6	9	1
Source-Drain Diode Ratings and Char	acteristics ^b						
Pulsed Current ^a	I _{SM}			-	-	160	Α
Forward Voltage	V _{SD}	F =	40 A, V _{GS} = 0 V	-	0.9	1.5	V

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

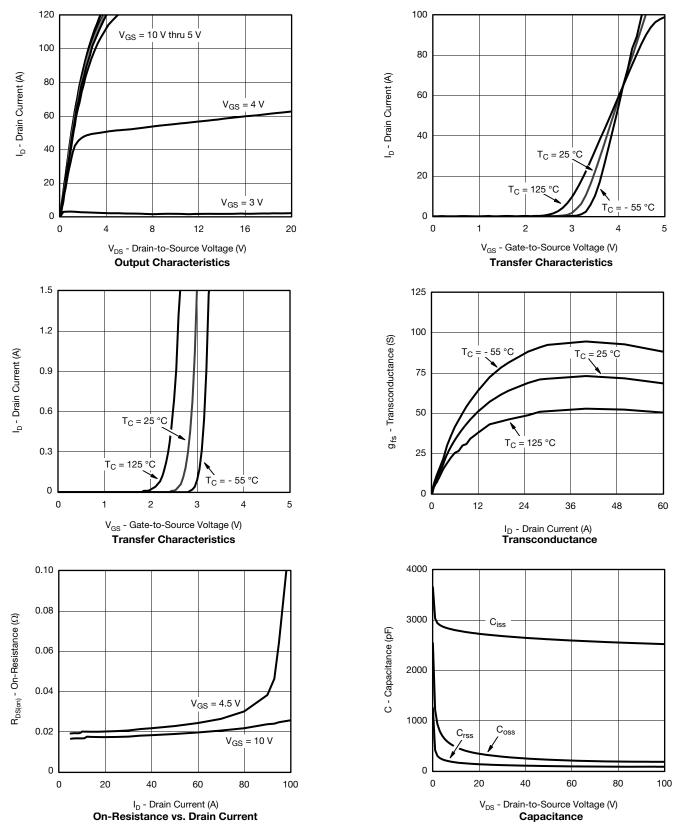
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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



S12-2198-Rev. E, 24-Sep-12

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V_{GS} = 10 V

50 75 100 125

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150 175

T_J = 150 °C

T_J = 25 °C

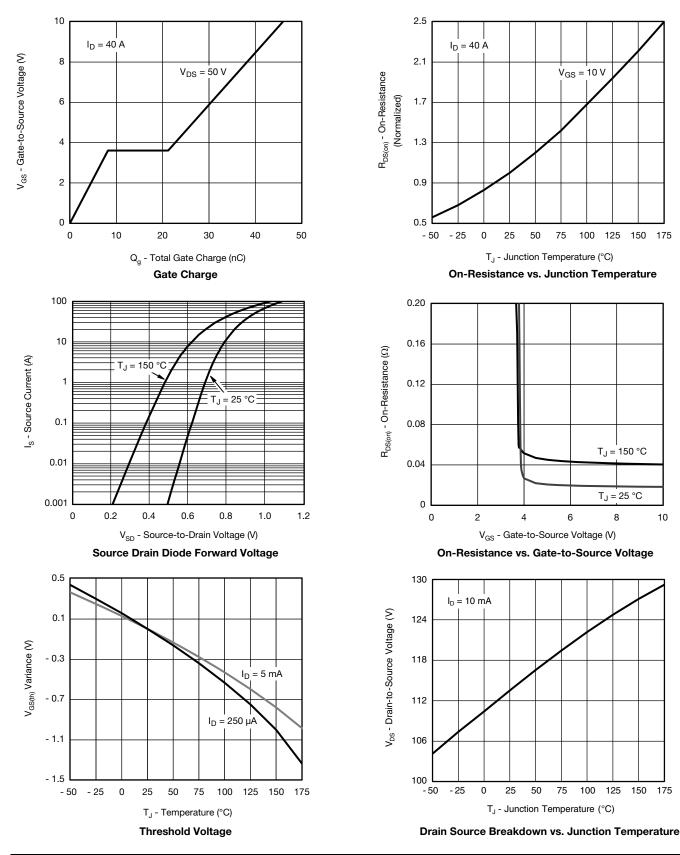
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50 75 100 125 150 175

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



S12-2198-Rev. E, 24-Sep-12

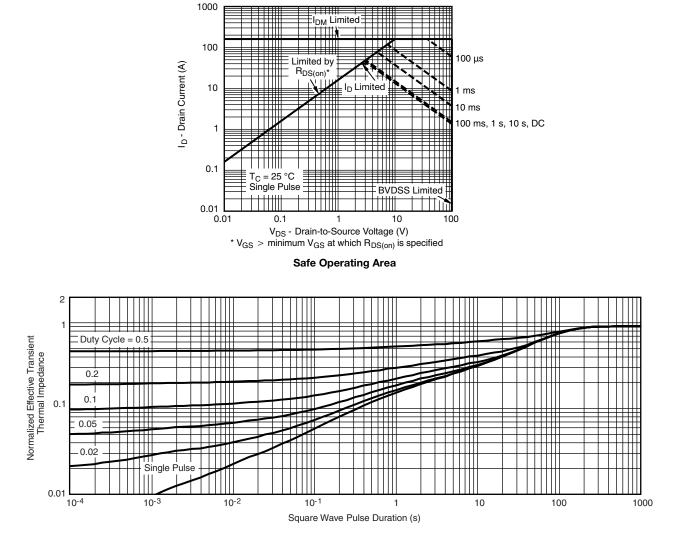
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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)

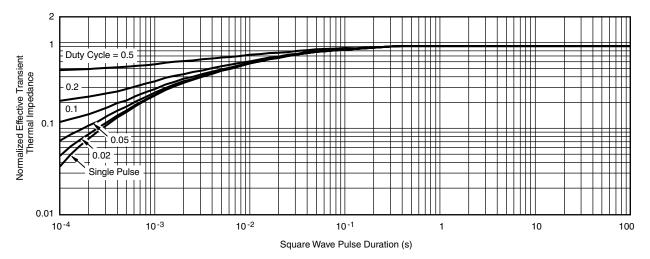


Normalized Thermal Transient Impedance, Junction-to-Ambient



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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

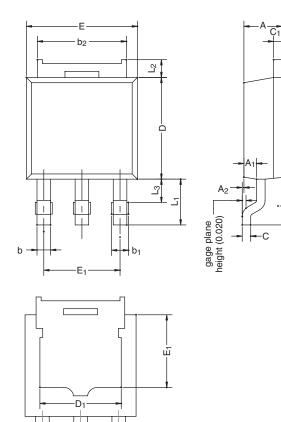
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TO-252 REVERSE LEAD CASE OUTLINE



	MILLIN	IETERS	INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.	
А	2.23	2.33	0.088	0.092	
A ₁	0.64	0.89	0.025	0.035	
A ₂	0.03	0.23	0.001	0.009	
b	0.71	0.88	0.028	0.035	
b ₁	0.76	1.14	0.030	0.045	
b ₂	5.23	5.44	0.206	0.214	
С	0.46	0.58	0.018	0.023	
C ₁	0.46	0.58	0.018	0.023	
D	5.97	6.22	0.235	0.245	
D ₁	4.49	5.00	0.177	0.197	
E	6.48	6.73	0.255	0.265	
E ₁	4.32	-	0.170	-	
е	2.28	BSC	0.090 BSC		
e ₁	4.57	4.57 BSC		BSC	
Н	9.65	10.41	0.380	0.410	
L	1.40	1.78	0.055	0.070	
L ₁	2.74 BSC		0.108	BSC	
L ₂	0.89	1.27	0.035	0.050	
L ₃	1.15	1.52	0.040	0.060	
ECN: T-08 DWG: 589	706-Rev. B, 29 4	9-Sep-08			

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Note

Dimension L_3 for reference only.

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